



SECOND PRELIMINARY AMENDMENT  
U.S. Application No. 10/588,659

Attorney Docket No.: Q96380

**AMENDMENTS TO THE SPECIFICATION**

**Please replace paragraph no. [0023] at page 16 of the specification with the following amended paragraph:**

In the semiconductor material according to the invention, moreover, a volume resistivity of the semiconductor material is equal to or higher than  $10^{-4}\Omega\text{cm}$  and is lower than  ~~$10^{-3}\Omega\text{cm}$~~   $10^3\Omega\text{cm}$ .

By this structure, the semiconductor material can be applied, as a p-type semiconductor or a hole injecting electrode layer, to a semiconductor device.